1. The register is a
2. Simplified unit of a subtractor
3. Cascaded group of the flip-flop
4. Binary ripple counter
5. Data selector
6. The energy of the photo electron depends upon the following factor
7. Intensity of incident radiation
8. Quality of the photocathode
9. Frequency of incident radiation
10. Type of the incident light source
11. Hall effect is used to determine
12. Magnetic flux
13. Current density
14. Type of semiconductor material
15. All of the above
16. Which one of the following is the thermistor
17. Semiconductor device
18. Microwave device
19. Platinum resistance thermometer
20. Thermo-couple device
21. Silicon is having direct band gap
22. True
23. False
24. No gap
25. None of these
26. Boron is doped in silicon to form
27. P-type
28. N-type
29. Intrinsic
30. None of these
31. The concentration of impurity in doped silicon semiconductor per atom is 1. 1018 b. 1022 c. 108 d. 10-22
32. Conduction in P-type semiconductor is due to
33. Movement of hole
34. Movement of electron
35. Movement of atoms
36. Movement of electron-hole pair
37. Slope of electrical conductivity Vs temperature in semiconductor is
38. Positive
39. Negative
40. Linear
41. No effect
42. Volt equivalent of temperature of silicon at room temperature ( 300 deg K ) is 1. 0.7 V b. 1.1 V c. 0.026 V d. 16 V

Answer

1. b2. c3. d4. d5. a6. a7. a8. a9. b10.
2. Carbon is not used as semiconductor because
3. It does not belong to silicon group
4. It is a good conductor
5. It is not a conductor
6. Band gap is very high
7. In forward bias of $\mathrm{P}-\mathrm{N}$ junction depletion region
8. Increases
9. Decreases
10. Remains the same
11. Breaks down
12. Knee voltage in diode stands for
13. Reverse break down voltage
14. Saturation voltage
15. Threshold of current conduction
16. Peak inverse voltage
17. An ideal semiconductor diode for an AC input acts like
18. Unidirectional switch
19. Bidirectional switch
20. Cuts off AC part
21. Power booster
22. Reverse saturation current in $\mathrm{P}-\mathrm{N}$ junction diode is due to
23. Hole conduction
24. Electron conduction
25. Minority carrier conduction
26. Majority carrier conduction
27. In the zener diode the break down in the reverse characteristic current is due to
28. Electrons
29. Hole
30. Electron hole pair
31. Crystal ions
32. The percentage of voltage regulation is defined as
33. V no load " V load r100 / V load
34. V load " V no load r100 / V load
35. V load " V no load r100 / V no load
36. V no load r100 / V load
37. Filtering is effected by shunting the load with a
38. Capacitor
39. Resistor
40. Inductor
41. None of these
42. Without applying the biasing voltage the transistor current would be
43. Maximum
44. Minimum
45. No change
46. Zero
47. In the transistor the doping at the emitter is much larger than the base results in
48. Emitter current entirely of holes
49. Emitter current entirely of electrons
50. Base current is due to electron-hole pair
51. Emitter does contribute carrier which can reach collector

Answers
c11. b12. b13. c14. a15. c16. c17. a18. a19. b20.
21. The largest current carrying component in P-N-P transistor is

1. Electrons
2. Holes
3. Electron hole pair
4. Silicon atoms
5. The circuit shown in the figure represents
6. Rectifier
7. Clamping circuit
8. Clipping circuit
9. Low pass filter
10. Clamping circuit is used for
11. AC to DC conversion
12. Biasing
13. Limiting the amplitude
14. Wave shaping
15. For ideal clipping circuit one should use a diode with cut-in voltage 1. 0.7 V b.1.1V c. 0 V d. 0.2 V
16. The ratio of peak inverse voltage of full wave and half wave rectifier is 1. 1 b. 2 c. $1 / 2$ d. $1 / 4$
17. Which of the following transistor configuration is a power amplifier
18. Common emitter
19. Common base
20. Common collector
21. All of the above
22. In a active mode of a transistor, collector conduction takes place due to
23. Majority carrier
24. Minority carrier
25. Common collector
26. All of the above
27. Common emitter configuration is used for a
28. Current amplification
29. Voltage amplification
30. Current and voltage amplification
31. Charge amplification
32. The transistor configuration where input is emitter and output is collector is called:
33. Common emitter
34. Common base common collector
35. Voltage follower(current gain)
36. Beta of a transistor is given by
37. lb/lc b. lc/lb c. lb/le d. lc/le

Answers
b21. b22. b23. c24. b25. a26. d27. a28. c29. b30.
31. Germanium transistor is preferred over silicon transistor in the following application

1. High frequency
2. High power
3. Low voltage
4. Power rectification
5. SCR is based on the principle of
6. Voltage regeneration
7. Current regeneration
8. Power regeneration
9. Power rectification
10. The number of clock pulses arriving at the digital counter input, should be in the form of
11. Decimal
12. Binary
13. Octal
14. Hexadecimal
15. In which of the counter the clock input is common to all flip flops
16. Asynchronous counter
17. Synchronous counter
18. Decade counter
19. Down counter
20. Multiplexer helps in which of the following
21. Repetition of similar circuit construction
22. Selecting all the signal at the output at the same time
23. Prevention of constructing similar circuits
24. Increase in the constructional costs due to repetition circuits
25. Full adder for two inputs can be developed with the help of
26. Two half adder on OR gate
27. One half adder and two OR gate
28. An EXOR gate and AND gate
29. Two AND gates and an OR gate
30. The important use of gray code is for a
31. Ripple counter
32. Full adder
33. Encoder
34. Decoder
35. In which of the code only one bit changes at each time
36. BCD
37. Aiken code
38. Excess 3 code
39. Gray code
40. In Johnson code for N bits, the maximum number can be formed is given by an expression
41. $2 . \mathrm{Nb}$. 2 N c. 2 N " 2 N d. None of these
42. The active mode of transistor operation is used in log circuits because of its
43. Non linearity
44. Linearity
45. Switching nature
46. High speed

Answers
b31. b32. c33. b34. b35. a 36. a37. c38. d39. b40. a
41. Intermediate frequency in television receiver is

1. $26-46 \mathrm{MHz}$
2. $1.6-2.3 \mathrm{MHz}$
3. $455-\mathrm{KHz}$
4. None of these
5. At absolute temperature, a silicon crystal acts like an insulator because
6. Electrons cannot move through a crystal
7. Electrons are tightly held by other atoms
8. Electrons can break away only by supplying energy
9. All of the above
10. Extrinsic semiconductor is
11. Doped with impurities
12. Exists in the pure state
13. N-type only
14. Only P-type
15. The process of extracting the audio information from the modulated envelope is called
16. Modulation
17. Detection
18. Transmission
19. Oscillation
20. Selectivity of a radio receiver is defined as
21. Ability to reproduce the original frequencies
22. Ability to eliminate wanted frequencies
23. Ability to reject unwanted frequencies
24. Ability to pick up the weak signal
25. Digital counter cannot be used as
26. Clock
27. Timer
28. Event counter
29. Multiplier
30. Distortion in the amplifier is due to
31. Non linearity of the device
32. Inductance presents in the circuits
33. Capacitance
34. Stray effect
35. The purpose of RF amplifier tuning in the radio receiver is
36. To reject all the frequencies
37. To select all the frequencies
38. Only to select required frequencies \& amplification
39. To vary the band width
40. The intermediate frequency used in the radio receiver is
41. 455 KHz b. $1.6 \mathrm{MHz} \mathrm{c}$.20 MHz d. 60 MHz
42. The purpose of using tuned circuit between stages in the radio receiver is
43. To increase the selectivity
44. To increase the sensitivity
45. To increase both selectivity and sensitivity
46. To get the detector output

## Answers

41. d42. d43. a44. b45. c46. d47. a48. c49. a50.
42. In an amplifier, the frequency characteristic may be divided into how many regions 1. Two b. Three c. Four d. Zero
43. Op.amp. has high input impedance because
44. High band width
45. Differential amplifier
46. Current source at input end
47. Common collector configuration
48. Gain of an OP amp. In inverting mode is "Rf / Rn provided, the OP.amp. has
49. Low output impedance
50. Low input bias current
51. High CMRR
52. High open loop gain
53. Slew rate of an OP.amp.is
54. Change of $O / p$ voltage with time
55. Propagation speed
56. Input RC time constant
57. Off set voltage drift
58. Instrumentation OP.amp. is used in application where
59. Two instrument are to be interfaced
60. Input is very low level signal
61. DC signals are involved
62. Differential signals are involved
63. An OP.amp. integrater will be
64. Capacitor at input
65. Diode at input
66. Diode feed back
67. Capacitor feed back
68. A logarithmic amplifier will have
69. Inductor feed back
70. Diode feed back
71. Resistance feed back
72. Thermistor feed back
73. OP.amp. can be converted into capacitor by
74. Increasing bandwidth
75. Removing feed back
76. Increasing input impedance
77. Positive feed back
78. Comparators are used as
79. Switching device
80. Linear amplifiers
81. Power amplifiers
82. High speed amplifiers
83. Typical output impedance of 741 OP amps. is
84. 0.5 W b. $1 \mathrm{~K} \mathrm{~W} \mathrm{c}$.

Answers
51. c52. b53. d54. b55. b56. d57. d58. a59. a60. a
61. Typical unity gain bandwidth of 741 OP amps. is

1. 10 MHz b. 100 KHzc . 1 MHz d. 1.5 MHz
2. OP.amp. wein bridge oscillator works when the over all gain is 1. 180 b. 3 c. 1.2 d. 125
3. Important part in a electronic voltage regulator is
4. Error amplifier
5. External pass transistor
6. Reference voltage diode
7. All the above
8. To generate a triangular wave form from a square wave
9. Differentiator is used
10. Integrator is used
11. Logarithmic amplifier is used
12. Clipping circuit is used
13. For multiplying two analog signals which one of the following is used
14. Comparator
15. Hall effect device
16. Gunn diode
17. Tunnel diode
18. Which of the following device is used as an electronic memory element
19. Astable multivibrator
20. Monostable multivibrator
21. Magnetic tape
22. None of these
23. Phase sensitive detector in lock-in-amplifier is used
24. To increase the sensitivity of an instrument
25. To limit the bandwidth
26. To increase the dynamic range of the signal
27. To increase the input impedance
28. In television transmission video signal is
29. Frequency modulated
30. Amplitude modulated
31. Phase modulated
32. delta modulated
33. The Boolean function $X Y Z+Y Z+X Z$, after simplification gives
34. $X$ b. $Y$ c. $Z$ d. $X+Y+Z$
35. Extremely low power dissipation and low cost per gate can be achieved in
36. MOS ICs
37. CMOS ICs
38. TTL ICs
39. ECL ICs

Answers
c61. a62. b63. d64. b65. a6. c7. b68. b69. c70. b
71. Which of the following digital IC families can give maximum fan-out

1. ECL b. PMOS c. HTL d. CMOS
2. A punched card has
3. 22 rows, 90 columns
4. 12 rows, 80 columns
5. 12 rows, 2 columns
6. 8 rows, 128 columns
7. Which one of the following is a 16 bit microprocessor
8. Zilog 80
9. Intel 8085
10. Motorola 6800
11. Intel 8086
12. (0.3125)10 when converted to base 8 gives
13. (0.16)8 b. (0.26)8 c. (0.24)8 d. (0.124)8
14. Excess " 3 code is a
15. Weighted code
16. Cyclic code
17. Error correcting code
18. Self complementing code
19. ASC II code is a
20. Error detecting code
21. Self correcting code
22. An alphanumeric code
23. A weighted code
24. Modulo " 2 addition is represented by
25. $f=X Y+X Y$
26. $f=X Y+X Y$
27. $f=X+X Y$
28. $f=X Y+X Z+Y Z$
29. Which one of the following Boolean identities is correct?
30. $X Y Z+Y Z+X Z=Y Z+X Z$
31. $X Y Z+Y Z+X Z=X Y+X Z$
32. $X Y+X Z=X Y+X Z+Y Z$
33. $X+X Y=X Y$
34. SN7410 IC is a
35. Quad 2 input NAND gate
36. Triple 3 input NAND gate
37. Dual M/S J-K flip flop
38. None of these
39. Intel 8085 microprocessor has two registers known as primary data pointers these are
40. Registers V \& C
41. Registers D \& E
42. Registers H \& L
43. None of these
44. Intel 8080 microprocessor has an instruction set of 91 instructions. The op-code to implement the instruction set should be at least
45. 6 bit b. 7 bytes c. 7 bit d. 8 bit
46. A micro programmed computer can have the following memories in its control memory unit
47. Semiconductor ROM
48. Semiconductor RAM
49. Magnetic RAM
50. None of these
51. In digital circuits parallel operation is preferred because
52. It requires less memory
53. Circuitry is simple
54. It is faster than series operation
55. For None of these of the above reasons
56. SN 7401 IC is a
57. Quad 2 input NAND gate
58. Quad 2 input NAND gate with open collector output
59. Quad single input NAND gate with open collector output
60. None of these
61. What is the binary code of (26)?
62. 11001 b. 10001 c. 11010 d. 10100
63. The basic RS flip flops is
64. A bistable multivibrator
65. A monostable multivibrator
66. An astable multivibrator
67. None of these
68. The input impedance of an operational amplifier is
69. Very small
70. Zero
71. Very high but not infinite
72. Infinite
73. Sn 7411 is
74. OP.amp. monolithic and short circuit protection in-built
75. Two input NAND gate
76. Three input NAND gate with open collector output
77. None of these
78. The output voltage of an operational amplifier is
79. 90 deg out of phase from the input
80. 90 deg out of phase from the input
81. 45 deg out of phase from the input
82. 180 deg out of phase from the input
83. The equivalent octal number of (492) is
84. 574 b. 547 c. 754 d. 758

## Answers

71. d72. b73. d 74. c75. d76. c77. a78. c79. b80. c81. c82. a83. b84. b85. c86. a87. c88. c89. d90. c
72. The equivalent decimal number for gray code 1011 is
73. 14 b. 13 c. 41 d. 31
74. The output will be only if all inputs go to 1 in case of 1. OR gate b. AND gate c. NAND gate d. NOT gate
75. Which of the following circuits is known as half adder?
76. AND circuit
77. OR circuit
78. Exclusive OR circuit
79. None of these
80. Which of the following memories is used to store variable quantities of the data?
81. RAM b. ROM c. PROM d. EPROM
82. Large scale Integrated (LSI) circuits usually contain
83. Less than 10 gates
84. 10 to 100 gates
85. more than 100 gates
86. more than 1000 gates
87. The Boolean expression $A+A B+B$ on simplification can be reduced to:

$$
\text { 1. } 0 \text { b. } 1 \text { c. } A+B d . A+B
$$

97. For realizing a decade counter using flip-flops the minimum number of flip-flops required is 1.4 b. 5 c. 6 d. 10
98. Which logic family is widely used in SSI \& MSI applications?
99. ECL b. DTL c. TTL d. None of these
100. An amplitude modulation detector detects
101. The peak value of the modulation signal
102. The envelop of the modulation signal
103. The peak value of the carrier signal
104. The average value of the carrier signal
105. Microwave (MW) links are generally preferred to coaxial cable for TV transmission because:
106. They have less overall phase distortion
107. They are cheaper
108. Of their greater bandwidth
109. Of their relative immunity to impulse noise.
110. b92. b93. c94. a95. c96. b97. a98. c99. b100. a
